

Josephson Circuits I.

Outline

1. RCSJ Model Review
2. Response to DC and AC Drives
 - Voltage standard
3. The DC SQUID
4. Tunable Josephson Junction

October 27, 2005

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JJ RCSJ Model as Circuit Element

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Please see: Figure 9.6, page 459, from Orlando, T., and K. Delin. *Foundations of Applied Superconductivity*. Reading, MA: Addison-Wesley, 1991. ISBN: 0201183234.

$$i = I_c \sin \varphi + \frac{v}{R} + C \frac{dv}{dt} \quad \text{and} \quad v = \frac{\Phi_o}{2\pi} \frac{d\varphi}{dt}$$

Therefore,

$$i = I_c \sin \varphi + \frac{\Phi_o}{2\pi R} \frac{d\varphi}{dt} + C \left(\frac{\Phi_o}{2\pi} \right)^2 \frac{d^2\varphi}{dt^2}$$

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DC Current Drive

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$$\beta_c = \frac{\tau_{RC}}{\tau_J} = \frac{R^2 C}{L_J} = \frac{2\pi I_c R^2 C}{\Phi_0}$$

A. Static Solution: $\varphi = \sin^{-1} \frac{i}{I_c}$ for $i \leq I_c$

B. Dynamical Solution

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DC Voltage Drive

The voltage source is DC with $v=V_0$, so that

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$$\varphi(t) = \varphi(0) + \frac{2\pi}{\Phi_0} V_0 t$$

The resulting current across the JJ is ac

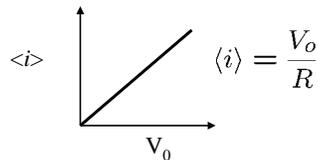
$$i_J = I_c \sin \left(\frac{2\pi}{\Phi_0} V_0 t + \varphi(0) \right)$$

The current across the resistor is dc

$$i_R = \frac{V_0}{R}$$

The total current is then

$$i = \frac{V_0}{R} + I_c \sin \left(\frac{2\pi}{\Phi_0} V_0 t + \varphi(0) \right)$$



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AC Voltage Drive

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The voltage source $v(t) = V_o + V_s \cos \omega_s t$

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Then the gauge-invariant phase is

$$\varphi(t) = \varphi(0) + \frac{2\pi}{\Phi_o} V_o t + \frac{2\pi V_s}{\Phi_o \omega_s} \sin \omega_s t$$

The resulting current across the JJ is

$$i_J = I_c \sin \left(\varphi(0) + \frac{2\pi}{\Phi_o} V_o t + \frac{2\pi V_s}{\Phi_o \omega_s} \sin \omega_s t \right)$$

The current across the resistor is

$$i_R(t) = \frac{V_o}{R} + \frac{V_s}{R} \cos \omega_s t$$

The current across the capacitor is $i_C(t) = -C V_s \omega_s \sin \omega_s t$

The total current is then $i(t) = i_R + i_J + i_C$

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AC Voltage Drive

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$$i(t) = \frac{V_o}{R} + I_c \sum_{n=-\infty}^{+\infty} (-1)^n J_n \left(\frac{2\pi V_s}{\Phi_o \omega_s} \right) \sin \varphi(0) \delta_{2\pi f_J, n \omega_s}$$

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AC Voltage vs Current Drives

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Voltage Standard

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Please see: NIST (public domain) <http://www.boulder.nist.gov/div814/div814/whatwedo/volt/dc/JVS.html>

10 V conventional Josephson voltage standard chip. The chip is 1 cm x 2 cm and contains 20,208 series connected Nb-AlO_x-Nb junctions.

<http://www.boulder.nist.gov/div814/div814/whatwedo/volt/dc/JVS.html>

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HYPRES: Voltage Standard Chip

HYPRES is the only commercial manufacturer of the superconducting integrated circuit used in Primary Voltage Standard Systems. HYPRES chips are used in the primary voltage standards in national laboratories around the world including Italy, France, United Kingdom, Australia, China, Malaysia, Japan, England, Canada, Norway, United States, Netherlands and Mexico.

The HYPRES Josephson Junction Array Voltage Standard circuits provide the ultimate accuracy for realizing and maintaining the SI Volt.

Features/Specifications

- Niobium/Aluminum Oxide/Niobium, SiO₂ dielectric, Niobium wiring technology.
- All Niobium technology. Refractory. Impervious to moisture and thermal cycling.
- 20,208 Josephson junctions (10 V chip) 3,660 Josephson junctions (1 V chip)
- 18 x 38 micrometers junction area.
- Installed in a FR-4 epoxy glass mount.
- RF input WR-12 waveguide flange.
- RF Distribution - 16 way parallel x 1263 cells in series (10 V) - 4 way parallel x 915 cells in series (1 V)
- Designed for a frequency range of 72-78 GHz
- Operating temperature of 4.2 K
- Common DC terminal resistance is < 1 Ohm - typical
- Approximately 10 mW operating power at the input flange for 10 V chip (2 mW for 1 V)
- -11V to +11 V range for 10 V chip.
- -2.5 V to + 2.5 V range for 1 V chip.
- Stability time is typically 1 hour for the 10 V chip, 5 hours for the 1V chip
- 0.005 PPM accuracy at 10 V (10 V chip)
- 0.05 PPM accuracy at 1V (1V chip)
- Calibration certificate supplied with each chip.
- Two (2) year warranty

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Parametric Inductor

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$$i(t) = I_c \sin \varphi(t) + \frac{v(t)}{R} + C \frac{d}{dt} v(t)$$

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Take the time derivative of the currents, and for the Josephson term:

$$\frac{d}{dt} i_J(t) = \left[\frac{2\pi I_c}{\Phi_o} \cos \varphi(t) \right] v(t)$$

The parametric (time-dependent) inductance can be defined as

$$L_J = \frac{\Phi_o}{2\pi I_c \cos \varphi(t)}$$

*On the zero-voltage branch, for $I_s \ll I_0$ and $I_0 + I_s \ll I_c$, then $I_0 \sim I_c \sin \phi$, so that

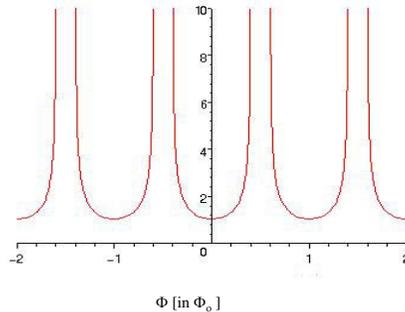
$$L_J \approx \frac{\Phi_o}{2\pi I_c \sqrt{1 - (I_0/I_c)^2}}$$

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Inductance along V=0 branch

$$L_J \approx \frac{\Phi_o}{2\pi I_c \sqrt{1 - (I_o/I_c)^2}}$$
$$L\left[\frac{\Phi_o}{2\pi I_c}\right]$$



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The DC SQUID (damped)

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Our goal is to show that the DC SQUID circuit in (a) is equivalent to the circuit for a single junction with an effective I_c and an effective resistance. The inductance of the SQUID loop in (a) is considered negligible.

In fact, we will also show later that there is an equivalent statement even for the underdamped case.

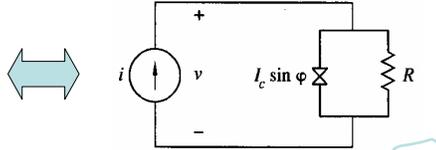
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DC SQUID Equivalent Circuit

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$$i = i_{J_1} + i_{J_2} + i_{R_1} + i_{R_2}$$

$$= I_{c1} \sin \varphi_1 + I_{c1} \sin \varphi_2 + \frac{v}{R_1} + \frac{v}{R_2}$$

Use flux quantization, $\varphi_2 - \varphi_1 = \frac{2\pi\Phi}{\Phi_0}$ and the fact that the junctions are identical

$$i = \underbrace{2I_{c1} \cos\left(\frac{\pi\Phi_{\text{ext}}}{\Phi_0}\right)}_{I_c} \sin\left(\varphi_1 + \frac{\pi\Phi_{\text{ext}}}{\Phi_0}\right) + \underbrace{\left(\frac{1}{R_1} + \frac{1}{R_2}\right)}_{1/R} v(t)$$

$$I = I_c \sin \varphi + \frac{1}{R} \Phi_0 \frac{d}{2\pi dt} \varphi$$

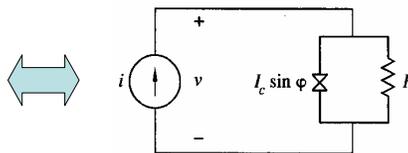
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DC SQUID Equivalent Circuit

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$$i = I_c \sin \varphi + \frac{1}{R} \frac{\Phi_0}{2\pi} \frac{d\varphi}{dt} \quad \text{with} \quad I_c = 2I_{c1} \cos\left(\frac{\pi\Phi_{\text{ext}}}{\Phi_0}\right)$$

Therefore, for this overdamped equivalent circuit, for $i > I_c$

$$\langle v(t) \rangle = iR \sqrt{1 - \left[\frac{2I_{c1}}{i} \cos\left(\frac{\pi\Phi_{\text{ext}}}{\Phi_0}\right) \right]^2} \quad \langle v(t) \rangle = iR \sqrt{1 - \left(\frac{i_{\text{max}}}{i}\right)^2}$$

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DC SQUID Voltage Modulation

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Please see: Figure 5.11a, page 272, from Van Duzen and Turner.

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DC SQUID Voltage Modulation

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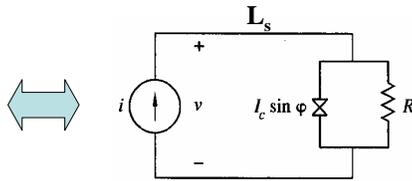
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DC SQUID Sensitivity

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Assume that $L_s > L_J = \Phi_0/2 \pi I_c(\Phi_{ext})$, then the range of modulation of the current is about

$$\delta i = i_{max}^+ - i_{max}^- \approx \Phi_0/L$$

The sensitivity of the output voltage to the input flux is

$$\frac{\delta \langle v \rangle}{\delta \Phi_{ext}} \approx \frac{R_D \delta i}{\frac{1}{2} \Phi_0} = \frac{2R_D}{L}$$

With $R_D \sim R = 1 \text{ Ohm}$ and $L \sim 1 \text{ nH}$, then the sensitivity is about one microvolt per flux quantum, so that small fractions of a flux quantum can be measured.

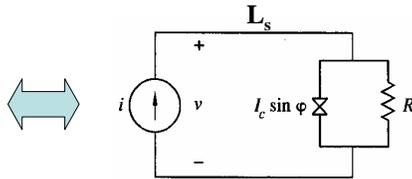
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DC SQUID and Thermal Noise

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Assume again that $L_s > L_J = \Phi_0/2 \pi I_c(\Phi_{ext})$, then to prevent thermal noise from effecting the SQUID's performance, one needs

Energy stored in the SQUID \gg Thermal Energy

$$\frac{1}{2} \frac{\Phi_0^2}{L} \gg \frac{1}{2} k_B T$$

Therefore, $L_s < 1 \text{ nH}$ at 4 K, and 0.1 nH at 100 K.

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Equivalent Tunable Junction

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$$I_c = 2I_{c1} \cos\left(\frac{\pi\Phi_{\text{ext}}}{\Phi_o}\right)$$

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Please see: Figure 9.1, page 486, from Orlando, T., and K. Delin.
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$$\frac{1}{R} = \frac{1}{R_1} + \frac{1}{R_2} \quad C = C_1 + C_2$$

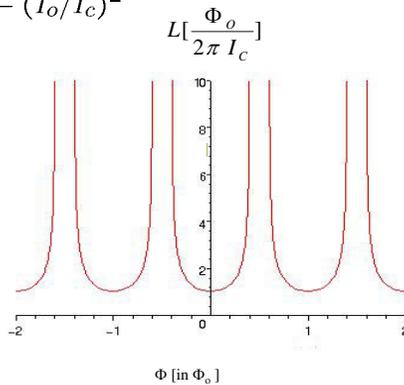
$$\beta_c = \frac{\tau_{RC}}{\tau_J} = \frac{R^2C}{L_J} = \frac{2\pi I_c R^2 C}{\Phi_o}$$

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Tunable Inductance along V=0 branch

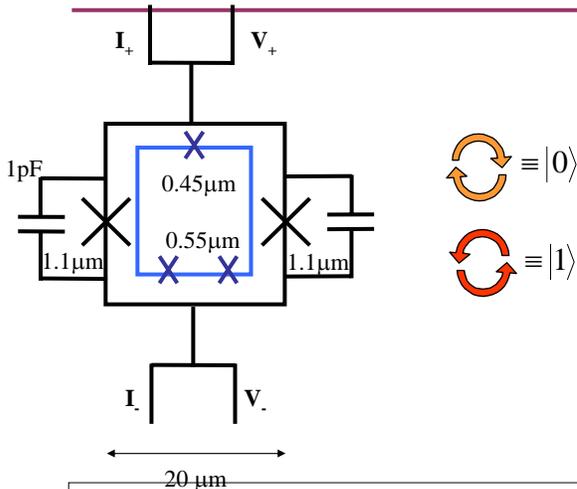
$$L_J \approx \frac{\Phi_o}{2\pi I_c \sqrt{1 - (I_o/I_c)^2}}$$



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Three-Junction Loop Measurements



Three-junction Loop
 Jct. Size ~ 0.45μm, 0.55μm
 Loop size ~16x16μm²
 L_{3-junction} ~ 30pH
 I_c ~1 & 2μA
 E_J/E_c ~ 350 & 550

DC SQUID
 Shunt capacitors ~ 1pF
 Jct. Size ~ 1.1μm
 Loop size ~20x20μm²
 L_{SQUID} ~ 50pH
 I_c ~10 & 20μA
 M ~35pH
 J_c ~350 & 730A/cm²

- Measure switching current of DC SQUID
- Vary external flux, temperature and SQUID ramp rate

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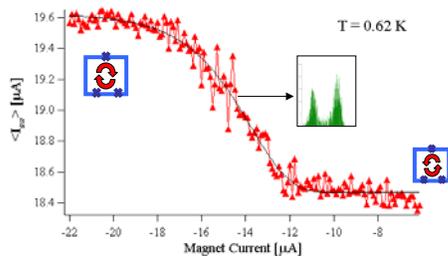
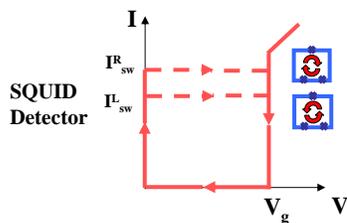
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Thermal Activation of Nb Persistent Current Qubit

5/6/03

SFQ on-chip oscillator and qubit
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	J _c	E _J	E _J /E _c	Jct. width	α	Q
Device A:	365 A/cm ²	2400 μeV	380	0.563 μm	0.613	1.0x10 ⁶
Device B:	730 A/cm ²	4000 μeV	560	0.529 μm	0.589	1.2x10 ⁶

Highest Q of any submicron Nb junction

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Coupling between qubits

